

# LBC807-16LT1G S-LBC807-16LT1G

General Purpose Transistors PNP Silicon

# **1. FEATURES**

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- Collector current capability IC = -500 mA.
- Collector-emitter voltage VCEO (max) = -45 V.
- General purpose switching and amplification.

# 2. DEVICE MARKING AND RESISTOR VALUES

Device	Marking	Shipping
LBC807-16LT1G	5A1	3000/Tape&Reel
LBC807-16LT3G	5A1	10000/Tape&Reel

### 3. MAXIMUM RATINGS(Ta = 25°C)

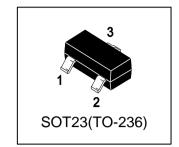
Parameter	Symbol	Limits	Unit
Collector-Emitter Voltage	VCEO	-45	V
Collector-Base Voltage	VCBO	-50	V
Emitter-Base Voltage	VEBO	-5	V
Continuous Collector Current	IC	-500	mA

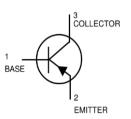
# **4. THERMAL CHARACTERISTICS**

Parameter	Symbol	Limits	Unit
Total Device Dissipation FR– 5 Board, (Note 1)			
$TA = 25^{\circ}C$	PD	225	mW
Derate above 25°C		1.8	mW/℃
Thermal resistance from junction to ambient	RθJA	556	°C/W
Total Device Dissipation			
Alumina Substrate, (Note 2) TA = 25°C	PD	300	mW
Derate above 25°C		2.4	mW/℃
Thermal resistance from junction to ambient	RθJA	417	°C/W
Junction and Storage Temperature	TJ, Tstg	-55~+150	°C

1. FR–5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.







# 5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

Characteristic	Symbol	Min.	Тур.	Max.	Unit	
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (IC = -10mA)	BVCEO	-45	-	-		
Collector-Base Breakdown Voltage (IC = -10µA)	BVCBO	-50	-	-	V	
Emitter-Base Breakdown Voltage (IE = -1µA)	BVEBO	-5	-	-		
Collector Cut-off Current (VCB =-20V) (VCB = -20 V, TJ = 150°C)	ICBO	-	-	-100 -5	nA μA	
Emitter-Base cut-off current (IC = 0, VEB = -5 V)	IEBO	-	-	-100	nA	
Collector-Emitter cutoff Current (VCE = -45V, IB=0)	ICEO	-	-	-5	μΑ	
ON CHARACTERISTICS						
DC Current Gain (IC = -100 mA, VCE = -1.0 V) (IC = -500 mA, VCE = -1.0 V)	hFE	100 40	-	250 -		
Collector-Emitter saturation Voltage (IC =-500mA, IB = -50mA)	VCE(sat)	-	-	-0.7	V	
Base–Emitter On Voltage (IC = -500 mA, VCE = -1.0 V)	VBE(on)	-	-	-1.2	V	
SMALL-SIGNAL CHARACTERISTICS	1					
Current–Gain — Bandwidth Product (IC = –10 mA, VCE = –5.0 V, f = 100 MHz)	fT	100	-	-	MHz	
Output Capacitance (VCB = -10 V, f = 1.0 MHz)	Cob	-	10	-	pF	



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### 6.OUTLINE AND DIMENSIONS

#### Notes:

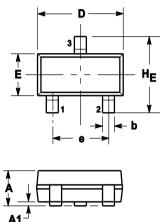
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

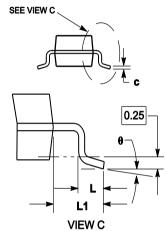
2. CONTROLLING DIMENSION: MILLIMETERS.

3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

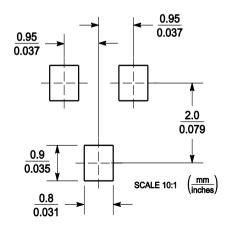
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1	1.11	0.035	0.04	0.044
A1	0.01	0.06	0.1	0.001	0.002	0.004
b	0.37	0.44	0.5	0.015	0.018	0.02
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.9	3.04	0.11	0.114	0.12
Е	1.20	1.3	1.4	0.047	0.051	0.055
е	1.78	1.9	2.04	0.07	0.075	0.081
L	0.10	0.2	0.3	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
H <sub>E</sub>	2.10	2.4	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°





7.SOLDERING FOOTPRINT





#### DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.
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